



HAL
open science

Two-fluid plasma model for ultrashort laser-induced electron-hole nanoplasmas

Benoît Morel, Remo Giust, Kazem Ardaneh, François Courvoisier

► **To cite this version:**

Benoît Morel, Remo Giust, Kazem Ardaneh, François Courvoisier. Two-fluid plasma model for ultrashort laser-induced electron-hole nanoplasmas. *Physical Review B*, 2022, 106 (3), pp.035207 (12). 10.1103/physRevB.106.035207 . hal-03813306

HAL Id: hal-03813306

<https://hal.science/hal-03813306>

Submitted on 13 Oct 2022

HAL is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers.

L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.

Two-fluid plasma model for ultrashort laser-induced electron-hole nanoplasmas

B. Morel,* R. Giust, K. Ardaneh, and F. Courvoisier[†]
*FEMTO-ST institute, Univ. Bourgogne-Franche-Comté, CNRS,
15B avenue des Montboucons, 25030, Besançon Cedex, France*

(Dated: August 29, 2022)

This is a pre-peer-review version of an article published in *Physical Review B*. The final version is available online at:

<https://link.aps.org/doi/10.1103/PhysRevB.106.035207>

We present a two-fluid plasma model to describe localized interaction, at sub-micrometer scale, of highly focused ultra-short laser pulses within dielectrics and semiconductors. This model includes transport of the electron-hole plasma, electron-hole scattering, photoionization, impact ionization and interactions between charge carriers and phonons. We start with a plasma kinetic description and we consistently derive the two-fluid plasma model equations. Our numerical results highlight that transport of the electron-hole plasma can strongly affect the plasma density profile in the case of extremely localized interaction.

I. INTRODUCTION

Ultrashort laser pulses are a powerful tool to induce modifications of materials¹⁻⁴. Particularly in transparent dielectrics, ultrashort laser pulses can be used to locally modify, inside the material's bulk, the chemical structure, the index of refraction, the density of color centers, photopolymerize, generate nano-gratings, surface nanostructures or internal voids. A large number of application fields benefit from fundamental advances: surgery and biomedical applications, photonics, microfluidics, high-speed laser manufacturing^{2,5-7}.

Pushing forward these applications to nanometric structuring requires the support of numerical modelling⁸. Under laser-induced strong-field, bound electrons transit from the valence band to the conduction band^{1,9,10}, leaving a hole in the valence band. Particles of the electron-hole plasma are accelerated in the laser field, which results in the multiplication of the free carrier density via impact ionization, and potentially in the creation of a dense electron-hole plasma. Finally, at timescales much larger than several picoseconds, thermal and structural events takes place inside the material¹. Our model is focused on the plasma density build-up, at timescales up to some picoseconds.

A large number of different models have been developed to study the propagation of ultra-short laser pulses (~ 100 fs) in the high-intensity regime ($\sim 10^{14}$ W/cm²) inside dielectrics and subsequent ionization. These models can be classified into two groups. In the first, several

models were developed to study the filamentation regime inside transparent solids with propagation scales on the order of several tens of micrometers^{11,12}. The pulse propagation model, such as the Unidirectional Pulse Propagation Equation¹³, is derived from Maxwell's equations and coupled with a rate equation for free electron generation¹⁴. These models are well suited to describe the spatio-temporal evolution of the pulse under the different linear and nonlinear phenomena: Kerr and Raman effects, group velocity dispersion, diffraction, nonlinear ionization, plasma absorption and recombinations. They can be refined to describe non-paraxial propagation^{15,16}. However, the derivation of the pulse propagation equation requires the assumptions of unidirectionality, local neutrality and transverse fields. These assumptions are not well suited to the case of nanoplasmas ($< 1 \mu\text{m}$) induced by tightly focused beams³.

In the second group, the models are intended to describe energy deposition in dielectrics at micrometric scale and are computationally very expensive because the full set of Maxwell equations is solved. Several descriptions of the plasma have been used: in references¹⁷⁻¹⁹, plasma formation and heating is described by rate equations. A more refined model is the single fluid hydrodynamic approach^{20,21}. An approach based on a two-temperature model (TTM) was used in Ref.²².

In these previous works, the transport phenomena is conventionally neglected since valence holes are conventionally heavy compared to the effective electron mass ($m_h^* = 5 - 10m_e$)^{21,23,24}. Because of Coulomb attraction, transport of electrons and holes remain quasi-

identical. The fluid of the heaviest particle (electron or hole) limit the transport of lightest one. If electron and hole have comparable light masses, then actual transport can be significant. Neglecting transport phenomena can be therefore inappropriate for materials with light holes such as sapphire²⁵, magnesium oxide²⁶, silicon²⁷, or zinc oxide²⁸. Ultrafast transport at high-speed (1.5×10^6 m/s) was recently observed experimentally in the latter material with pump-probe imaging-ellipsometry²⁸. A density-dependent two temperature model (nTTM) was recently developed²⁹ and includes the electron-holes transport in semi-conductors. This model describes the evolution of free carrier density, carriers temperature, lattice temperature, density and energy transport, but hypothesizes plasma neutrality and same temperature for conduction electrons and valence holes.

Here, we propose a more general theoretical description of laser-induced excitation of dielectrics and semi-conductors, that takes into account the transport phenomena and hence is valid for any effective mass ratio. We will particularly emphasize here the case where mass ratio is around 1, since it is the case that differs at most from the state of the art described above. In this case, we observed a significant transport, but also important consequences resulting from the holes dynamics (modification of the cut-off frequency, additional impact ionization, warm holes). Our fluid model includes 5-moments transport equations for each fluid, photoionization, impact ionization, electron-hole scattering and interactions between carriers and phonons. The approach is only valid when the band structure of the material remains, and is intended to describe the transient regime before the occurrence of nonthermal melting³⁰ or of the transformation of the plasma into warm dense matter^{31–33}.

The paper is organized as follows: in section II, we recall the two-fluid plasma model equations for an electron-hole plasma inside a bandgap material with parabolic energy bands, and we briefly review the different physical phenomena included in the model. In section III, we derive the source terms describing respectively electron-hole scattering, interactions between carriers and phonons, photoionization and impact ionization. Finally, in section IV, our numerical results of Bessel beam interaction with sapphire highlight that transport can significantly affect the plasma profile, throughout extremely localized interactions inducing nano-plasmas.

II. THE TWO-FLUID PLASMA MODEL

The fluid model developed in this article is intended for materials that can be described by an isotropic parabolic band structure: the effective masses of conduction electrons and valence holes are independent of direction and position in Brillouin zone.

The fluid model can be derived consistently by calculating moments of the kinetic equation with respect to velocity³⁴ and by assuming a local thermodynamic equilibrium³⁵ for electrons and holes. This implies Maxwellian distributions for both particle species. The fluid description allows saving computational effort in comparison with the kinetic approach³⁶. In our case, we consider that the plasma is sufficiently collisional to keep the particles distribution close to a Maxwellian distribution. The equations of two-fluid plasma model under balance laws form (*i.e.* a conservative form on the left side of fluid equations and a source term on the right one) are given by^{37,38}:

$$\frac{\partial}{\partial t} \begin{bmatrix} n_e \\ n_e \mathbf{u}_e \\ \epsilon_e \\ n_h \\ n_h \mathbf{u}_h \\ \epsilon_h \end{bmatrix} + \nabla \cdot \begin{bmatrix} n_e \mathbf{u}_e \\ n_e \mathbf{u}_e \otimes \mathbf{u}_e + \frac{p_e}{m_e^*} \mathbf{I} \\ (\epsilon_e + p_e) \mathbf{u}_e \\ n_h \mathbf{u}_h \\ n_h \mathbf{u}_h \otimes \mathbf{u}_h + \frac{p_h}{m_h^*} \mathbf{I} \\ (\epsilon_h + p_h) \mathbf{u}_h \end{bmatrix} = \begin{bmatrix} 0 \\ \frac{n_e q_e}{m_e^*} (\mathbf{E} + \mathbf{u}_e \times \mathbf{B}) \\ n_e q_e \mathbf{u}_e \cdot \mathbf{E} \\ 0 \\ \frac{n_h q_h}{m_h^*} (\mathbf{E} + \mathbf{u}_h \times \mathbf{B}) \\ n_h q_h \mathbf{u}_h \cdot \mathbf{E} \end{bmatrix} + \begin{bmatrix} \mathbf{S}_e^{\text{Coll}} \\ \mathbf{S}_h^{\text{Coll}} \end{bmatrix} \quad (1)$$

The system of equations (1) corresponds to three conservation's laws for each fluids (electrons and holes): conservation of particles number, momentum and energy. The term with the divergence operator is called the transport term whereas the terms on the right member is called the source terms. For a specie of particles a ($a = e$ for conduction electrons and $a = h$ for valence holes), q_a is the electric charge, m_a^* the effective mass, n_a the density, \mathbf{u}_a the mean velocity, p_a the scalar pressure, ϵ_a the fluid energy density, \mathbf{E} the electric field and \mathbf{B} the magnetic field. \mathbf{I} is the identity matrix and \otimes is tensor product. To obtain the system of equations (1), we additionally

made the assumption that electrons and holes fluids are non-viscous. The effects of viscosity are usually unimportant in ultra-fast dynamics³⁹. It allows us to consider scalar pressures instead of pressure tensors.

The system of equations for electrons and hole fluids is closed by assuming local thermodynamic equilibrium (Maxwellian distribution) for both species:

$$\epsilon_a \equiv \frac{p_a}{\gamma - 1} + \frac{1}{2} n_a m_a^* \mathbf{u}_a^2 \quad (2)$$

where γ is the adiabatic index. The local thermodynamic equilibrium allows linking pressure and temper-

ature through the ideal gas law³⁵: $p_a = n_a k_B T_a$, where T_a is the temperature and k_B the Boltzmann constant.

The terms $\mathbf{S}_e^{\text{Coll}}$ and $\mathbf{S}_h^{\text{Coll}}$ are the collisional terms for electron and hole fluids. We use the same general method

as in Ref.^{40,41} in order to include different physical phenomena, *i.e.* we split the collisional terms of Eq. (1) in several terms:

$$\begin{aligned} \begin{bmatrix} \mathbf{S}_e^{\text{Coll}} \\ \mathbf{S}_h^{\text{Coll}} \end{bmatrix} &\equiv \underbrace{\begin{bmatrix} \mathbf{S}_e^{e-h} \\ \mathbf{S}_h^{e-h} \end{bmatrix}}_{\equiv \mathbf{S}^{e-h}} + \underbrace{\begin{bmatrix} \mathbf{S}_e^{\text{Imp-e}} \\ \mathbf{S}_h^{\text{Imp-e}} \end{bmatrix}}_{\equiv \mathbf{S}^{\text{Imp-e}}} + \underbrace{\begin{bmatrix} \mathbf{S}_e^{\text{Imp-h}} \\ \mathbf{S}_h^{\text{Imp-h}} \end{bmatrix}}_{\equiv \mathbf{S}^{\text{Imp-h}}} + \underbrace{\begin{bmatrix} \mathbf{S}_e^{\text{Ph}} \\ \mathbf{S}_h^{\text{Ph}} \end{bmatrix}}_{\equiv \mathbf{S}^{\text{Ph}}} + \underbrace{\begin{bmatrix} \mathbf{S}_e^{e-p} \\ \mathbf{S}_h^{e-p} \end{bmatrix}}_{\equiv \mathbf{S}^{e-p}} + \underbrace{\begin{bmatrix} \mathbf{S}_e^{h-p} \\ \mathbf{S}_h^{h-p} \end{bmatrix}}_{\equiv \mathbf{S}^{h-p}} \end{aligned} \quad (3)$$

where the superscript *e-h* is related to electrons-holes scattering, *e-p* to interactions between electrons and phonons, *h-p* to interactions between holes and phonons, *Ph* to photoionization, *Imp-e* to electron-initiated impact ionization and *Imp-h* to hole-initiated impact ionization.

The electric and magnetic fields in Eq. (1) are determined by Maxwell equations:

$$\nabla \cdot \varepsilon_r \mathbf{E} = \frac{1}{\varepsilon_0} [q_e n_e + q_h n_h] \quad (4)$$

$$\nabla \cdot \mathbf{B} = 0 \quad (5)$$

$$\nabla \times \mathbf{E} = -\frac{\partial \mathbf{B}}{\partial t} \quad (6)$$

$$\nabla \times \mathbf{B} = \mu_0 \mathbf{J} + \frac{1}{c^2} \frac{\partial \varepsilon_r \mathbf{E}}{\partial t} \quad (7)$$

where ε_0 and μ_0 are respectively the vacuum permittivity and permeability. $c = (\varepsilon_0 \mu_0)^{-1/2}$ is the speed of light. ε_r is the relative permittivity of the background dielectric. The total current density \mathbf{J} is composed of the contribution from conduction electrons and of the one from valence holes:

$$\mathbf{J} = q_e n_e \mathbf{u}_e + q_h n_h \mathbf{u}_h \quad (8)$$

In our description, we consider an electron-hole plasma localized in background dielectric of relative permittivity ε_r . The effect of bound charges is also taken into account through relative permittivity ε_r whereas the effect

of charge carriers is included through the current density \mathbf{J} of Eq. (8).

We finally remark that, here, the medium response to an electromagnetic excitation is taken into account through a fluid approach. This approach is valid only when the spatial scales are larger than the Debye length⁴². The typical densities involved in numerical results of section IV are around 10^{21} cm^{-3} and the temperatures are in a range of 1-100 eV, leading to a Debye length between 0.2 nm and 2 nm.

III. COLLISIONAL SOURCE TERMS

In this section, we specify the source terms $\mathbf{S}_e^{\text{Coll}}$ and $\mathbf{S}_h^{\text{Coll}}$ of Eq. (3). We include the different physical phenomena one by one in our model.

A. Electron-hole scattering

We start with the elastic scattering between conduction electrons and valence holes. We have chosen to include this phenomenon via the Bhatnagar-Gross-Krook (BGK) approach⁴³. This approach assumes that the elastic scattering restores a local equilibrium with an exponential decay in time. This description usually gives a first approximation to the problem under consideration³⁵ and is relatively easy to link to the Drude model of plasmas⁴⁴. The inclusion of the BGK term in the two-fluid plasma equations is performed via the following source term⁴⁵:

$$\mathbf{S}^{e-h} = \begin{bmatrix} \mathbf{S}_e^{e-h} \\ \mathbf{S}_h^{e-h} \end{bmatrix} = \begin{bmatrix} 0 & -n_e \nu_{eh} \frac{\mu}{m_e^*} (\mathbf{u}_e - \mathbf{u}_h) \\ -\frac{\kappa \nu_{eh} n_e}{\gamma-1} (T_e - T_h) + \frac{\kappa \nu_{eh} n_e}{2} (m_e^* \mathbf{u}_e^2 - m_h^* \mathbf{u}_h^2 + (m_h^* - m_e^*) \mathbf{u}_e \cdot \mathbf{u}_h) & 0 \\ 0 & -n_h \nu_{he} \frac{\mu}{m_h^*} (\mathbf{u}_h - \mathbf{u}_e) \\ -\frac{\kappa \nu_{he} n_h}{\gamma-1} (T_h - T_e) + \frac{\kappa \nu_{he} n_h}{2} (m_h^* \mathbf{u}_h^2 - m_e^* \mathbf{u}_e^2 + (m_e^* - m_h^*) \mathbf{u}_h \cdot \mathbf{u}_e) & 0 \end{bmatrix} \quad (9)$$

where $\mu = \frac{m_e^* m_h^*}{m_e^* + m_h^*}$ is the reduced mass, $\kappa = \frac{2\mu}{m_e^* + m_h^*}$ and ν_{eh} is the scattering frequency for momentum transfer

from electrons to holes whereas ν_{he} is from holes to elec-

trons. Eq. (9) is symmetrical to the permutation $e \leftrightarrow h$, and conservation of momentum and energy imposes the following condition⁴⁵:

$$n_e \nu_{eh} = n_h \nu_{he} \quad (10)$$

B. Interactions between charge carriers and phonons

As in Ref.⁴¹, we consider two scattering phenomena for the interactions between charge carriers and phonons. The first one is the charge carrier - phonon elastic scattering, where charge carriers undergo a momentum change due to phonon emission/absorption. The second phenomenon is the carrier-phonon-photon interaction. In these two phenomena, the loss of energy to the phonon bath is negligible at sub-picosecond timescale^{9,33}. The impact of these scattering events on the conduction electron fluid and on the valence hole fluid is a modification of the distribution of the particle, *i.e.*, a reduction of the mean velocity and an increase of the thermal energy. We include these phenomena in a classical way (*i.e.*, in a non-quantum treatment) via frictions terms²³:

$$\mathbf{S}^{e-p} = \begin{bmatrix} \mathbf{S}_e^{e-p} \\ \mathbf{S}_h^{e-p} \end{bmatrix} \equiv \begin{bmatrix} 0 \\ -n_e(\nu_{epp} + \nu_{ep})\mathbf{u}_e \\ 0 \\ 0 \\ \mathbf{0} \\ 0 \end{bmatrix} \quad (11)$$

where ν_{epp} is the electron-phonon-photon interaction rate and ν_{ep} is the electron-phonon scattering rate. Similarly, we have for the hole fluid:

$$\mathbf{S}^{h-p} = \begin{bmatrix} \mathbf{S}_e^{h-p} \\ \mathbf{S}_h^{h-p} \end{bmatrix} \equiv \begin{bmatrix} 0 \\ \mathbf{0} \\ 0 \\ 0 \\ -n_h(\nu_{hpp} + \nu_{hp})\mathbf{u}_h \\ 0 \end{bmatrix} \quad (12)$$

where ν_{hpp} is the hole-phonon-photon interaction rate and ν_{hp} is the hole-phonon scattering rate.

In this description with friction terms, the total energies ϵ_a of the fluids do not change (no term in components 3 and 6 of Eq. (11) and Eq. (12)). The scattering induces a conversion of directed energy $\frac{1}{2}n_a m_a^* \mathbf{u}_a^2$ into thermal energy $\frac{p_a}{\gamma-1}$. It also induces a weakening of the current density \mathbf{J} , thus absorbing energy from the electromagnetic fields.

We note that here, we discard the energy transfer from the carriers to the phonon bath since it is effective at timescales of several picoseconds while our model is intended to model typically sub-picosecond dynamics^{9,33}.

C. Electron-electron and hole-hole scattering

Electron-electron and hole-hole elastic scattering do not affect fluid equations (1)^{29,35}. The reason is that in the fluid approach, the shape of the distribution is fixed to a Maxwellian one, before and after the scattering process. In addition, during a scattering event, the change of momentum (resp. energy) of a particle is equal to the change of momentum (resp. energy) of the other particle. This implies that the total momentum (resp. energy) of the fluid remain constant during elastic scattering between particles of same specie³⁵.

D. Photoionization

Photoionization, impact ionization and recombination can be considered as inelastic collisions.³⁵ However, it is conventionally difficult to rigorously describe inelastic collisions in the framework of the fluid description⁴⁶. In this section, we insert photoionization (promotion of electrons in the conduction band by absorption of field energy) in the two-fluid plasma model. Impact ionization will be modelled in the following section. We start by defining n_{ev} as the density of electron available in the valence band: this number is a function of time and space. We set n_0 as the initial density of electron available in the valence band, and α^{Ph} as the photoionization rate in $m^{-3}s^{-1}$.

To include photoionization, we make the following assumptions: (i) the number of created fluid particles (electrons and holes) through photoionization is given by rate equation used in Ref.¹⁷ ($\frac{\partial}{\partial t}n_e = \frac{n_{ev}}{n_0}\alpha^{Ph}$). We use the Keldysh ionization rate in solid⁴⁷ (appendix A), but it could be replaced by more sophisticated models⁴⁸ without changing the overall architecture of our model. (ii) as in Ref.⁴⁹, we consider that during photoionization, valence electrons are promoted to the bottom of the conduction band. This is equivalent to neglecting the residual energy transfer to charge carriers after photoionization: fluid particles are generated with zero energy ($p_a = 0$ and $\mathbf{u}_a = \mathbf{0}$).

The source term for photoionization of Eq. (3) is therefore given by:

$$\mathbf{S}^{Ph} \equiv \begin{bmatrix} \mathbf{S}_e^{Ph} \\ \mathbf{S}_h^{Ph} \end{bmatrix} \equiv \begin{bmatrix} \frac{n_{ev}}{n_0}\alpha^{Ph} \\ \mathbf{0} \\ 0 \\ \frac{n_{ev}}{n_0}\alpha^{Ph} \\ \mathbf{0} \\ 0 \end{bmatrix} \quad (13)$$

For each electron-hole pair generated, one valence electron must be removed. This leads to the following rate equation for the density of valence electrons:

$$\frac{\partial}{\partial t}n_{ev} = -\frac{n_{ev}}{n_0}\alpha^{Ph} \quad (14)$$